

SOT89 OUTLINE

Description:

The MMA710 is a fully matched amplifier fabricated in Aeroflex / Metelics reliable InGap HBT technology. The economical SOT89 package provides excellent wideband performance.

Features:

- DC - 4 GHz Broadband Gain Block
- \pm 0.5 dB Typical Gain Flatness
- 50 Ohms Input/Output Impedances •

RF Specifications:

Parameter	Term	Minimum	Typical	Maximum	Units
3dB Bandwidth	BW	DC		4	GHz
Frequency Range	f _o	DC		4	GHz
Gain	G _P	12	13		dB
Output Power	$P_{_{1dB}}$	+18	+20		dBm
Input Standing Wave Ratio	VSWR		1.5:1	2.0:1	
Outut Standing Wave Ratio	VSWR		2.0:1	3.6:1	
3 rd Order Intercept Point	IP3	+34	+37		dBm
Noise Figure	NF		5.0	6.0	dB
Device Current	I _c	85	95	110	mA
NOTES: 1. $T_{A} = +25 \text{ °C}.$					

1. $T_A = +25$ °C.

2. $\hat{V}_s = 8.0$ Vdc, $R_{BIAS} = 11 \Omega$ 3. IP3 measured with two tones offset 10 MHz at 0 dBm per tone.

Absolute Maximum Ratings:

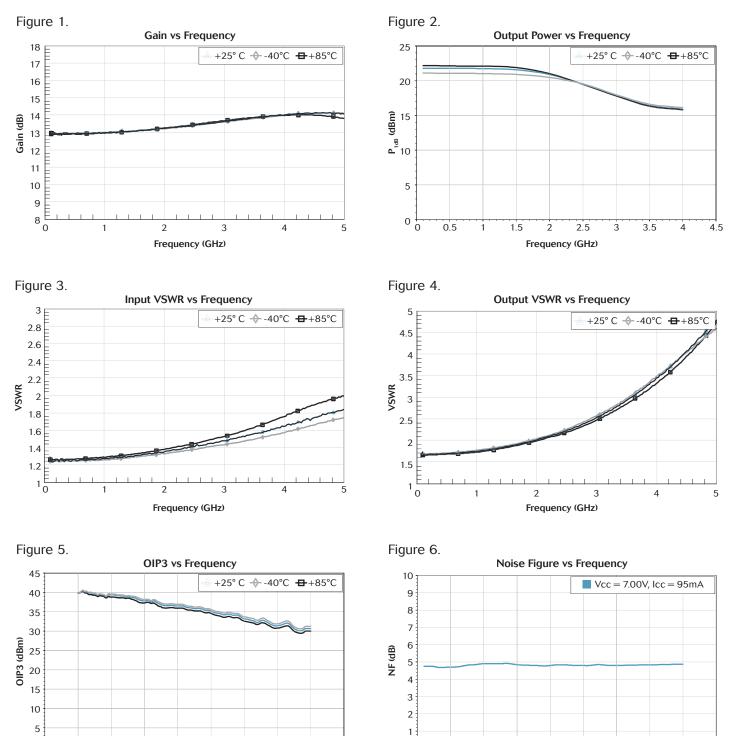
Parameters	Rating		
Device Current (I_c)	150 mA		
RF Input Power, continuous	+13 dBm		
Operating Temperature	-40 to +85 °C		
Storage Temperature	-55 to +125 °C		
Thermal Resistance (θ_{JC})	70 °C/W		







Typical RF Performance:



0∔ 0

0.5

1

1.5

2

Frequency (GHz)

2.5

ż

3.5

4

4.5

0 ↓ 0

2

0.5

1

1.5

2.5

ż

Frequency (GHz)

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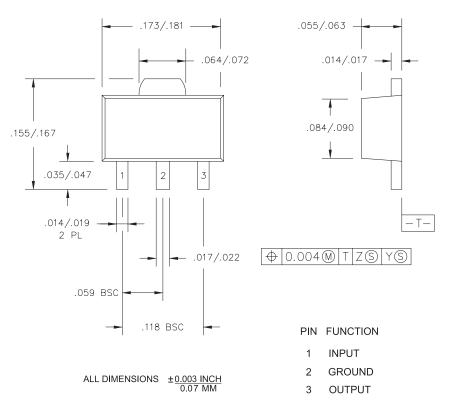
3.5

4

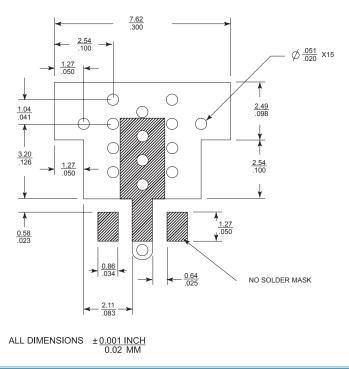
4.5



SOT89 Outline Dimensions:



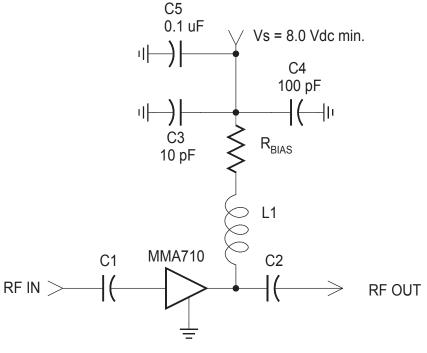
Recommended PCB Layout:



Aeroflex / Metelics, Inc. www.aeroflex-metelics.com



Application Circuit:



C1, C2, L1: X_L >> 50 Ω , X_C << 50 Ω

R_{BIAS} vs. V_{S}							
V _s (V)	8.0	10.0	12.0	15.0			
R _{BIAS} (Ω)	11	30	51	86			
Power Dissipation (W)	0.1	0.3	0.5	0.8			

